Alloy-Stabilized Semiconducting and Magnetic Zinc-Blende Phase of MnTe

Su-Huai Wei and Alex Zunger
Solar Energy Research Institute, Golden, Colorado 80401
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While MnTe has the stable NiAs structure with a direct band gap of 1.30 eV and a Mn-Te bond length of 2.92 Å, extrapolation of the data for the zinc-blende alloy Cd$_{1-x}$Mn$_x$Te to $x = 1$ suggests an alloy-stabilized MnTe phase with very different properties: a band gap of ~3 eV and a Mn-Te bond length of 2.73 Å. We model the structural, magnetic, and electronic properties of such a hitherto unknown zinc-blende-like MnTe phase through spin-polarized total-energy calculations, and report its unusual properties in both ferromagnetic and antiferromagnetic spin ordering.

For the vast majority of bulk solid solutions of isovalent binary $AC$ and $BC$ semiconductors, neither the $AC$ nor the $BC$ sublattices alter in the alloy the symmetry of their Bravais lattices.\(^1\) Such is the case for most pseudobinary IV-IV, III-V, II-VI, and I-VII isostructural alloys, which, despite substitutional disorder\(^2\) or tendencies to order,\(^3\) retain in solution their diamondlike, zinc-blende, wurtzite, and rocksalt substructures, respectively. In addition to these ("type I") alloys, there exists a smaller class (denoted here as "type II") of semiconductor alloys which, as a function of composition $x$, undergo a transition from one structure to another, where both structural forms are known to exist in the phase diagrams of the isolated $AC$ and $BC$ crystals. Such are, for example, the alloys (CdS)$_x$(ZnSe)$_{1-x}$, (CdS)$_x$(ZnS)$_{1-x}$, (CdSe)$_x$(CeTe)$_{1-x}$, and (CdSe)$_x$(HeSe)$_{1-x}$, which transform at some critical composition from the wurtzite to the zinc-blende structure. Interestingly, there exists a third, yet smaller class of alloys (denoted here as "type III") whose observed properties as a function of composition suggest that one component acquires a fundamentally new Bravais lattice, hitherto unknown to exist in its own phase diagram. Such are the magnetic semiconductor alloys of MnS, MnSe, and MnTe with a II-VI compound.\(^7\) While unusual structural forms of alloys have been known to form in extreme nonequilibrium growth methods\(^8\) and in epilayers,\(^7\) it is remarkable that alloy-stabilized phases with no counterpart in the phase diagram of the constituent components can be formed in bulk equilibrium growth. We first demonstrate from the data that such an unusual, alloy-stabilized zinc-blende phase is likely to exist in Cd$_{1-x}$Mn$_x$Te alloys, and then describe its structural, electronic, and magnetic properties through first-principles spin-polarized total-energy and band-structure calculations.

MnTe crystallizes below 1040 °C in the hexagonal NiAs structure\(^10\) (NaCl structure at higher temperatures\(^10\)) with a direct band gap\(^11\) of $E_g$(MnTe) = 1.30 eV and bond length\(^10\) $R$(Mn–Te) = 2.92 Å. Zinc-blende CdTe has a low-temperature gap\(^12\) $E_g$(CeTe) = 1.59 eV and bond length\(^13\) $R$(Cd–Te) = 2.80 Å. The solid lines in Fig. 1 depict the observed variations with composition of the fundamental band gap\(^14\) [Fig. 1(a)] and bond lengths\(^15\) [Fig. 1(b)] in the Cd$_{1-x}$Mn$_x$Te alloy. Expectations based on similar measurements in "normal" isostructural alloys\(^1\)

![Graph](image-url)

FIG. 1. Observed variations with composition $x$ of (a) the fundamental band gap (Ref. 14), and (b) bond lengths (Ref. 15) in Cd$_{1-x}$Mn$_x$Te. Dashed lines are extrapolations; dotted lines are expectations for "normal" isovalent alloys.

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(types I and II above) suggest (dotted lines in Fig. 1) that as Mn is added to CdTe the band gap will decrease (with a possible bowing), approaching the smaller value of MnTe, and the Mn—Te bond length will either increase slightly, or stay nearly constant around its value of 2.92 Å in MnTe. Experimental observations\textsuperscript{14,15} (Fig. 1) indicate instead that the opposite is true: For compositions below \( x = 0.7 \), for which single-phase samples can be prepared,\textsuperscript{13,14} the band gap increases and the Mn—Te bond length decreases slightly with added Mn. A rough extrapolation of the data from \( x \leq 0.42 \) to \( x = 1 \) (dashed lines in Fig. 1) suggests a “limiting MnTe phase” with \( E_g \approx 3.1 \text{ eV} \) and \( R (\text{Mn—Te}) = 2.73 \text{ Å} \). A similar extrapolation for \( \text{Hg}_1-x\text{Mn}_x\text{Te} \) also gives similar values of \( E_g \approx 3.3 \text{ eV} \) and \( R (\text{Mn—Te}) \approx 2.74 \text{ Å} \). The differences between the properties of this “limiting MnTe phase” and those of normal\textsuperscript{10,11} MnTe are so dramatic that we are inclined to think that this phase corresponds to a hitherto unknown new structure of MnTe, with fundamentally new properties.

To clarify the properties that such a material might have, we have performed self-consistent, local-density, spin-polarized total-energy and band-structure calculations for a few phases of MnTe with Bravais lattices similar to those observed for the alloy.\textsuperscript{15} We use the semirelativistic general-potential linear augmented plane-wave method\textsuperscript{16} with the Von Barthe-Hedin exchange-correlation potential, muffin-tin radii of 2.53 a.u. for all atoms, and about 90 basis functions per atom. The uncertainty in the calculated total-energy differences for the cubic phases is estimated to be about 0.05 eV, and about 0.1 eV when compared to the hexagonal phase. Figure 2 depicts the calculated variations with bond length of the total energies of ferromagnetic (F) and antiferromagnetic (AF) MnTe in the zinc-blende (ZB) structures (inset to Fig. 2). We find as follows: (i) The AF phase is stabler than the F phase by 0.19 eV/atom-pair; the two phases have similar bond lengths of \( R (\text{Mn—Te}) = 2.70 \pm 0.02 \text{ Å} \), close to the value of 2.73 Å extrapolated from the experimental data [Fig. 1(b)] for the “limiting phase.” (ii) While these phases have substantial cohesion relative to free atoms (7.37 and 7.56 eV/atom-pair for the F and AF phases, respectively), we calculate that the observed AF-NiAs structure is stabler by 0.40 and 0.21 eV/atom-pair relative to the zinc-blende F and AF forms, respectively. Hence, we would not expect to find the isolated ZB phase under conditions where equilibration to the NiAs form is not hindered by activation barriers. (iii) While the absolute value of local spin-density band gaps cannot be meaningfully compared with experiment, the relative differences in the gaps are far more realistic.\textsuperscript{17} We calculate that the ZB phases of MnTe have a \( p \rightarrow s \) band gap that exceeds that calculated for CdTe by 2.1 eV (and \( p-d \) and \( d-d \) gaps that are 0.9 eV larger than MnTe in the NiAs structure; see below).

Our calculations hence suggest the possibility of a cubic phase of MnTe with properties which are similar to those inferred for the “limiting phase” from the data on \( \text{Cd}_x\text{Mn}_{1-x}\text{Te} \). Such a phase is predicted, however, to be metastable when isolated in bulk form. Can this metastability barrier be lowered in the alloy? To address this question we have performed similar calculations for the \( \text{Cd}_0.5\text{Mn}_0.5\text{Te} \) alloy in the ordered CuAu-I ferromagnetic structure, i.e., CeMnTe\(_2\). In addition to its cubic lattice constant \( a \), the CuAu-I structure\textsuperscript{6} has an internal structural degree of freedom, i.e., the anion displacement parameter, given by \( u = \frac{1}{2} + \left( R^2_4 - R^2_5 \right)/a^2 \), measuring the possible mismatch in the two bond lengths \( R_{4C} \) and \( R_{5C} \) in the unit cell (i.e., \( \text{Mn—Te} \) and \( \text{Cd—Te} \)). We have minimized the total energy \( E (\text{CdMnTe}_2 , a , u) \) as a function of \( u \) and \( a \), finding at equilibrium \( a_{eq} = 6.37 \text{ Å} \) and \( u_{eq} = 0.242 \). These values correspond to \( R (\text{Mn—Te}) = 2.73 \text{ Å} \) and \( R (\text{Cd—Te}) = 2.79 \text{ Å} \), which are within 1% of the values observed for the 50%-50% alloy in extended x-ray absorption fine-structure measurements\textsuperscript{15} [arrows in Fig. 1(b)]. The fact that these values are also close to those of the pure end-point compounds suggests that the system has used its internal degree of freedom \( u \) to achieve nearly ideal bond lengths, thereby lowering its strain energy.\textsuperscript{2a} Evaluating the enthalpy of formation (per four atoms) for the ferromagnetic phases relative to
the equilibrium ZB forms of CdTe and F-MnTe,

\[ \Delta H = E_{\text{CdMnTe}_2} - E_{\text{MnTe}} \]

we find a negative value of \( \Delta H = -0.05 \) eV. Hence, the CuAu-I phase of F-CdMnTe\(_2\) is predicted to be stable against disproportionation into its ZB constituents. Whereas AF-CdMnTe\(_2\) has even a lower total energy than F-CdMnTe\(_2\), it is unstable with respect to AF-MnTe+CdTe by at least 0.04 eV, suggesting the possibility of clustering of the Mn-rich alloy into domains of AF-MnTe. While the F or AF alloy is still less stable relative to the NiAs structure, coherent strain activation barriers, posed by the large lattice relaxation needed to transform the ZB structure to the NiAs structure, suggest that, once formed, the ZB phase may persist. Furthermore, recent theoretical studies on epitaxial confinement suggest that if the ZB phase is grown on a substrate with a different lattice constant, substrate strain effects may further stabilize it. Experimental attempts to grow and characterize these structures are called for.

In Fig. 3 we show the calculated band structures of ferromagnetic CdMnTe\(_2\); we find that the spin-up Mn \( d \) band is occupied, centered at \( E^\uparrow_0 = 3.7 \) eV [Fig. 3(a)], whereas the spin-down \( d \) band is empty, centered at \( E^\downarrow_0 = 2.9 \) eV [Fig. 3(b)]. The +4.9-eV separation between them constitutes the effective \( d \)-band exchange (x) splitting \( \Delta_0(x) \). Remarkably, we find that the \( p-d \) exchange splitting \( \Delta_0(pd) = E^\uparrow_0 - E^\downarrow_0 \) of the top of the valence band is negative. The top of the valence band for spin up \( (E^\uparrow_0) \), having in the muffin-tin spheres 20% Mn \( d \) and 2×24% Te \( p \) character) is 1.7 eV above the top of the valence band for spin down \( (E^\downarrow_0) \), with 22% Mn \( d \) and 2×21% Te \( p \) character). This is at first surprising, given the fact that we find the effective potential for the majority spin to be more attractive than that for the minority spin, as is usually the case in spin-polarized systems. Figure 4 explains this phenomenon in terms of a simple \( p-d \) repulsion model. What is special about Mn and Te (as well as Mn-S and Mn-Se) is that the calculated atomic \( p \) and \( p \) orbital energies of the anion are bracketed by the atomic \( d \) and \( d \) levels of Mn (Fig. 4). In the tetrahedral crystal field, the anion \( p \) states have the \( t_2 \) (\( \Gamma_1 \)) symmetry and the metal \( d \) states are split into a doublet with \( e \) (\( \Gamma_2 \)) symmetry and a triplet with \( t_2 \) (\( \Gamma_3 \)) symmetry; the \( e \) states are lower than the \( t_2 \) states, there is no \( p-d \) hybridization between them. On the other hand, the coupling between the spin-up states with the same \( t_2 \) symmetry produces a lower bonding \( (B_+) \) and a higher antibonding \( (AB+) \) levels; the coupling between the spin-down states with the same \( t_2 \) symmetry produces similarly a lower bonding \( (B_-) \) and a higher antibonding \( (AB-) \) pair. Since the unperturbed \( d \) is below \( p \), but \( d \) is above \( p \), simple perturbation theory leads to the situation where \( B_- \) is below \( AB_+ \), and hence an effective negative \( pd \) exchange splitting. This \( p-d \) coupling mechanism, used previously to explain the anomalously small band gaps of ternary \( 3d \) semiconductors, suggests also here a smaller spin-up band gap (calculated: 0.63 eV) than the spin-down band gap (1.64 eV). The same phenomenon occurs for F-MnTe. This covalent \( p-d \) hybridization is also found to reduce the local

![FIG. 3. Electronic band structure of F-CeMnTe\(_2\) (a and b). The zero of the energy is at \( E^\uparrow_0 \). Symbols in parenthesis are the points of fcc Brillouin zone.](image)

![FIG. 4. Schematic diagram of the \( p-d \)-repulsion effect, for ferromagnetic CdMnTe\(_2\).](image)
magnetic moment of Mn from its free-space value of 5.0μμB to 4.30μμB, and even produces a small local magnetic moment of 0.09μμB and 0.05μμB on the otherwise nonmagnetic Te and Cd sites, respectively. In the AF spin arrangement the negative p-d exchange splitting will disappear. This is because there are equal numbers of Mn atoms with 3d levels below and above the Te p levels; the latter are repelled equally by d↑ and d↓, and hence no exchange splitting occurs for Te p states. Furthermore, since the p↑-d↑ hybridization is stronger than the p↓-d↓ hybridization, the difference in spin symmetry between the F and AF phases also indicates the enhanced stability of the AF structure: the stronger p-d repulsion in the F phase reduces the cohesion of the p bands.

The reason that the band gap of CdTe increases upon addition of Mn [Fig. 1(a)] with almost zero bowing can be simply explained in terms of the limiting phase being ZB rather than NiAs. We find the calculated interband p-s transition energy to be 1.43 eV; this is close to the average (1.48 eV) of our calculated p-s energies of the end-point compounds, i.e., Ep*(CdTe) = 0.44 eV and Ep*(F-MnTe) = 2.53 eV, suggesting a vanishing optical bowing. We conclude that the initial increase of the band gap of CdTe with added Mn [Fig. 1(a)] is due to the interband p-s transition. When the Mn concentration is increased, the conduction cation s states recede to higher energies relative to the Mn 3d↓ states (which, being more localized, are not as sensitive to composition changes); hence the excitations will then acquire a Te, p → Mn d↑ character with large atomiclike multiplet effects.

The exchange-interaction coefficients can be estimated from our first-principles total-energy and band-structure calculation. The calculated nearest-neighbor interaction energy Jnn between the localized Mn magnetic moments is found to be −16 K at the calculated lattice constant and −15 K at the extrapolated lattice constant. The exchange constants Nαα and Nαβ, which are responsible for the unique properties of Cd1−xMnxTe, are found to be 0.41 and −1.09, respectively. These are in satisfactory agreement with experiments and a recent theoretical calculation.

In summary, our calculation indicates that the alloy environment stabilizes a hitherto unknown ZB phase of MnTe and that in its ferromagnetic form it has a negative p-d exchange splitting and small magnetic moments even on the nonmagnetic ions (Cd, Te). The exchange-interaction coefficients have been estimated from our first-principles calculations.

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FIG. 3. Electronic band structure of F-CeMnTe₂ (a and b). The zero of the energy is at $E_F$. Symbols in parenthesis are the points of fcc Brillouin zone.
FIG. 4. Schematic diagram of the \( p-d \) repulsion effect, for ferromagnetic CdMnTe\(_2\).